



DMN2400UV

Product Summary

| BV _{DSS} | R _{DS(ON)} Max | I _D Max T _A = +25°C |
|-------------------|-------------------------------|--|
| 001/ | 0.48Ω @ V _{GS} = 5V | 1.33A |
| 20V | 0.7Ω @ V _{GS} = 2.5V | 1.2A |

Description

This new generation MOSFET has been designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

Applications

- **Power Management Functions**
- Battery Operated Systems and Solid-State Relays
- Load Switch

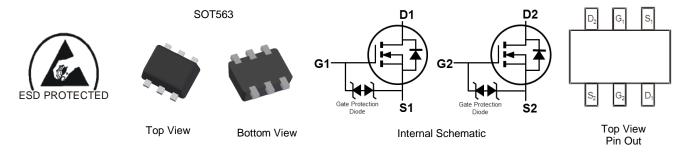
DUAL N-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Gate Threshold Voltage
- Low Input Capacitance
- Fast Switching Speed
- Low Input/Output Leakage
- **ESD Protected Gate**
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)
- For automotive applications requiring specific change control (i.e. parts qualified to AEC-Q101, PPAP capable, and manufactured in IATF 16949 certified facilities), please contact us or your local Diodes representative.
- https://www.diodes.com/guality/product-definitions/

Mechanical Data

- Case: SOT563
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections: See Diagram
- Terminals: Finish Matte Tin Annealed over Copper Leadframe. Solderable per MIL-STD-202, Method 208 @3
- Weight: 0.003 grams (Approximate)



Ordering Information (Note 4)

| | Part Number | Case | Packaging | | | |
|--|--------------|--------|--------------------|--|--|--|
| | DMN2400UV-7 | SOT563 | 3,000/Tape & Reel | | | |
| | DMN2400UV-13 | SOT563 | 10,000/Tape & Reel | | | |
| Notes: 1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant. | | | | | | |

1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information

| 24N YM | NAB YN |
|--------|--------|
| | |

24N and NAB = Marking Code YM = Date Code Marking Y = Year (ex: G = 2019)

M = Month (ex: 9 = September)

Date Code Key

| Date Obde Rey | | | | | | | | | | | | |
|---------------|-----|-----|-----|-----|------|-----|-----|------|-----|------|-----|------|
| Year | 200 | 9 | ~ | | 2019 | 20 | 20 | 2021 | | 2022 | 1 | 2023 |
| Code | W | | ~ | | G | | H | | | J | | K |
| Month | Jan | Feb | Mar | Apr | May | Jun | Jul | Aug | Sep | Oct | Nov | Dec |
| Code | 1 | 2 | 3 | 4 | 5 | 6 | 7 | 8 | 9 | 0 | Ν | D |



Maximum Ratings (@T_A = +25°C, unless otherwise specified.)

| Characterist | ic | | Symbol | Value | Unit |
|-----------------------------------|--|------------------|-----------------|--------------|------|
| Drain-Source Voltage | | V _{DSS} | 20 | V | |
| Gate-Source Voltage | | V _{GSS} | ±12 | V | |
| Continuous Drain Current (Note 5) | 5) Steady $T_A = +25^{\circ}C$ State $T_A = +85^{\circ}C$ | | ID | 1.33 0.84 | А |
| Pulsed Drain Current | | | I _{DM} | 3 | А |

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Value | Unit |
|---|----------------------------------|-------------|------|
| Total Power Dissipation (Note 5) | PD | 530 | mW |
| Thermal Resistance, Junction to Ambient | $R_{	heta JA}$ | 233.8 | °C/W |
| Operating and Storage Temperature Range | T _{J,} T _{STG} | -55 to +150 | С° |

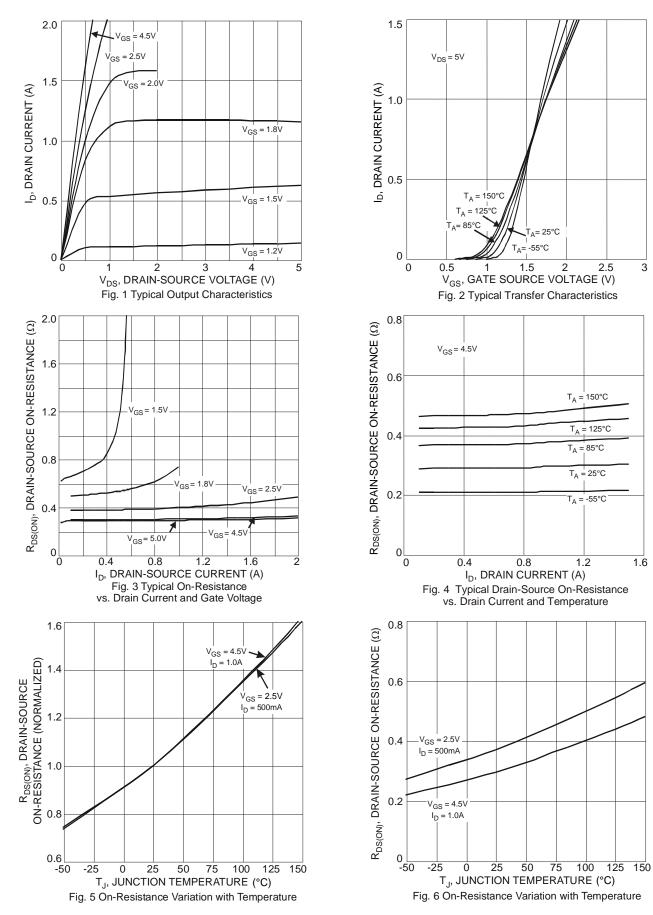
Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

| Characteristic | Symbol | Min | Тур | Max | Unit | Test Condition | |
|--|---------------------|-----|-------|------|------|--|--|
| OFF CHARACTERISTICS (Note 6) | | | | | | | |
| Drain-Source Breakdown Voltage | BV _{DSS} | 20 | - | | V | $V_{GS} = 0V, I_D = 250 \mu A$ | |
| Zero Gate Voltage Drain Current $T_J = +25^{\circ}C$ | I _{DSS} | — | — | 100 | nA | $V_{DS} = 20V, V_{GS} = 0V$ | |
| Gate-Source Leakage | la sa | _ | - | ±1.0 | ^ | $V_{GS} = \pm 4.5 V, V_{DS} = 0 V$ | |
| Gale-Source Leakage | I _{GSS} | _ | - | ±50 | μA | $V_{GS} = \pm 10V, V_{DS} = 0V$ | |
| ON CHARACTERISTICS (Note 6) | | | | | | | |
| Gate Threshold Voltage | V _{GS(TH)} | 0.5 | — | 0.9 | V | $V_{DS} = V_{GS}, I_D = 250 \mu A$ | |
| | | — | 0.3 | 0.48 | | $V_{GS} = 5.0V, I_D = 200mA$ | |
| | | — | 0.35 | 0.5 | | $V_{GS} = 4.5V, I_D = 600mA$ | |
| Static Drain-Source On-Resistance | R _{DS(ON)} | — | 0.45 | 0.7 | Ω | $V_{GS} = 2.5V, I_D = 500mA$ | |
| | | _ | 0.55 | 0.9 | | $V_{GS} = 1.8V, I_D = 350mA$ | |
| | | — | 0.65 | 1.5 | | $V_{GS} = 1.5V, I_D = 50mA$ | |
| Forward Transfer Admittance | Y _{fs} | _ | 1.4 | _ | S | $V_{DS} = 10V, I_D = 400mA$ | |
| Diode Forward Voltage (Note 6) | V _{SD} | _ | 0.7 | 1.2 | V | $V_{GS} = 0V, I_S = 150mA,$ f = 1.0MHz | |
| DYNAMIC CHARACTERISTICS (Note 7) | 1 | | | | | | |
| Input Capacitance | Ciss | _ | 36.0 | | pF | | |
| Output Capacitance | C _{oss} | _ | 5.7 | — | pF | V _{DS} =16V, V _{GS} = 0V, f = 1.0MHz | |
| Reverse Transfer Capacitance | Crss | | 4.2 | | pF | | |
| Gate Resistance | Rg | _ | 68 | — | Ω | $V_{DS} = 0V, V_{GS} = 0V$ | |
| Total Gate Charge | Qq | — | 0.5 | — | nC | | |
| Gate-Source Charge | Q _{gs} | | 0.07 | | nC | $V_{GS} = 4.5V, V_{DS} = 10V,$ | |
| Gate-Drain Charge | Q _{gd} | | 0.1 | | nC | I _D =250mA | |
| Turn-On Delay Time | t _{D(ON)} | _ | 4.06 | | ns | | |
| Turn-On Rise Time | t _R | _ | 7.28 | — | ns | $V_{DD} = 10V, V_{GS} = 4.5V,$ | |
| Turn-Off Delay Time | t _{D(OFF)} | _ | 13.74 | — | ns | $R_{L} = 47\Omega, R_{G} = 10\Omega,$ $D_{D} = 200 \text{mA}$ | |
| Turn-Off Fall Time | tF | _ | 10.54 | — | ns | ID = 200 mA | |

5. Device soldered onto FR-4 PCB, minimum recommended soldering pad dimensions (25.4mm x 25.4mm x1.6mm, 2oz Cu pad: 0.18mm² x 6). Notes: 6. Short duration pulse test used to minimize self-heating effect.
7. Guaranteed by design. Not subject to product testing.

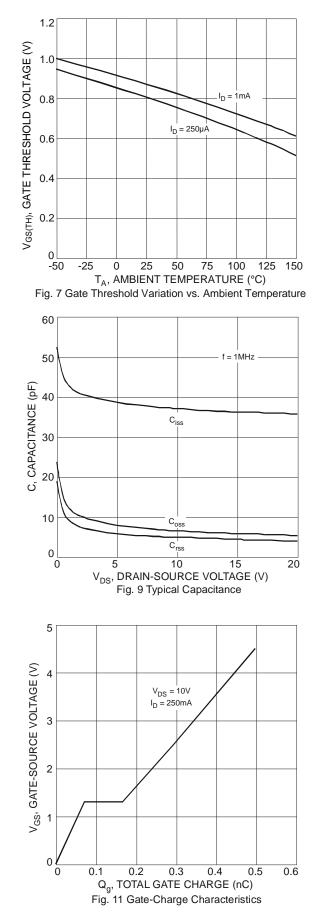


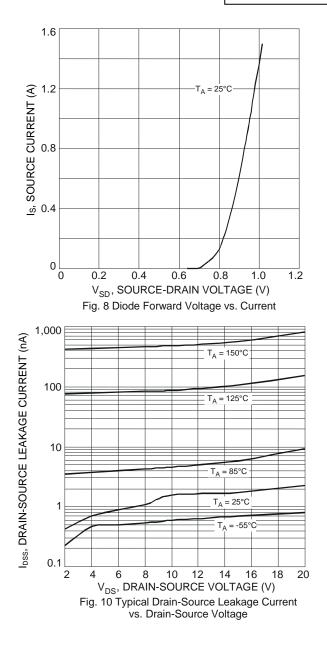
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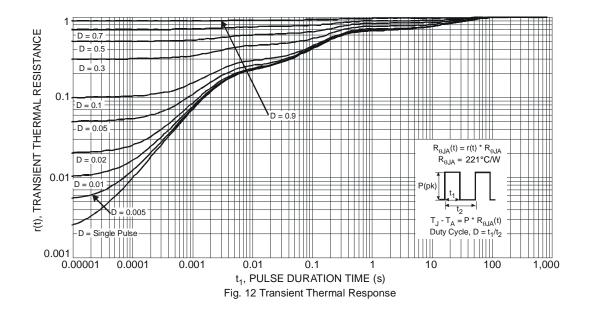
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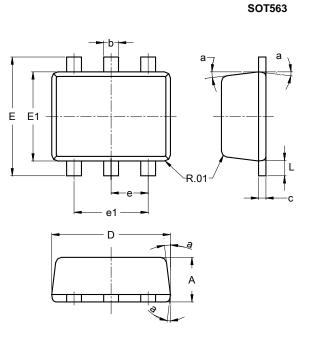






Package Outline Dimensions

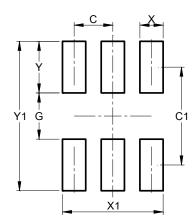
Please see http://www.diodes.com/package-outlines.html for the latest version.



| SOT563 | | | | | | | | |
|--------|--------|----------|------|--|--|--|--|--|
| Dim | Min | Max | Тур | | | | | |
| Α | 0.55 | 0.60 | 0.60 | | | | | |
| b | 0.15 | 0.30 | 0.20 | | | | | |
| С | 0.10 | 0.18 | 0.11 | | | | | |
| D | 1.50 | 1.70 | 1.60 | | | | | |
| Е | 1.55 | 1.70 | 1.60 | | | | | |
| E1 | 1.10 | 1.25 | 1.20 | | | | | |
| е | | | 0.50 | | | | | |
| e1 | 0.90 | 1.10 | 1.00 | | | | | |
| L | 0.10 | 0.30 | 0.20 | | | | | |
| а | 8° | 9° | 7° | | | | | |
| All | Dimens | sions in | mm | | | | | |

Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



SOT563

| Dimensions | Value (in mm) |
|------------|------------------|
| С | 0.500 |
| C1 | 1.270 |
| G | 0.600 |
| Х | 0.300 |
| X1 | 1.300 |
| Y | 0.670 |
| Y1 | 1.940 |



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